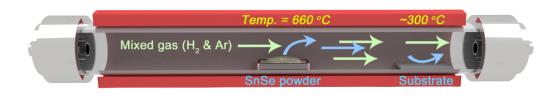
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Supplementary Information

Growth Mechanism of Vertically Aligned SnSe Nanosheets via Physical Vapour Deposition

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Scheme S1. A schematic illustration of the experimental setup using in the experiment

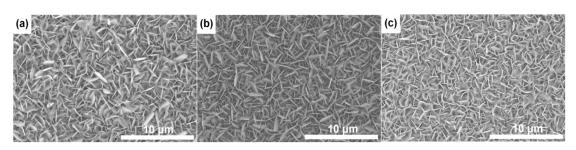


Fig. S1. FESEM images of SnSe nanosheets grown on (a) Si, (b) SiO₂ and (c) FTO glass.